

# INVENTOR INFORMATION

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Inventor Two Given Name:: Kiyoshi  
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## CORRESPONDENCE INFORMATION

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## APPLICATION INFORMATION

Title Line One:: NONVOLATILE MEMORY, SEMICONDUCTOR DEVICE  
Title Line Two:: AND METHOD OF MANUFACTURING THE SAME  
Total Drawing Sheets:: 13  
Formal Drawings?: Yes  
Application Type:: Utility  
Docket Number:: 740756-2255  
Secrecy Order in Parent Appl.?: No

## REPRESENTATIVE INFORMATION

Registration Number One:: 35483  
Registration Number Two:: 38285  
Registration Number Three:: 45285  
Registration Number Four:: 20932  
Registration Number Five:: 26477

## PRIOR FOREIGN APPLICATIONS

Foreign Application One:: 2000-023656  
Filing Date:: -01-2000  
Country:: Japan  
Priority Claimed:: Yes

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